



TLV431

1.24V COST EFFECTIVE SHUNT REGULATOR

Description

The TLV431 is a three-terminal, adjustable shunt regulator offering excellent temperature stability and output current handling capability up to 20mA. The output voltage may be set to any chosen voltage between 1.24V and 18V by selection of two external divider resistors.

The TLV431 can be used as a replacement for zener diodes in many applications requiring an improvement in zener performance.

The TLV431 is available in three grades with initial tolerances of 1%, 0.5%, and 0.2% for the A, B, and T grades respectively.

Features

- Low-Voltage Operation V_{REF} = 1.24V
- Temperature Range -40 to +125°C
- Reference Voltage Tolerance at +25°C

0.2% TLV431T

■ 0.5% TLV431B

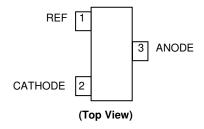
■ 1% TLV431A

- Typical Temperature Drift
 - 4mV (0°C to +70°C)
 - 6mV (-40°C to +85°C)
 - 11mV (-40°C to +125°C)
- 80µA Minimum Cathode Current
- 0.25Ω Typical Output Impedance
- Adjustable Output Voltage V_{REF} to 18V
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (TLV431Q)

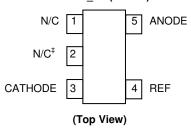
Pin Assignments

TLV431 F (SOT23)

(Top View)



TLV431_E5 (SOT25)



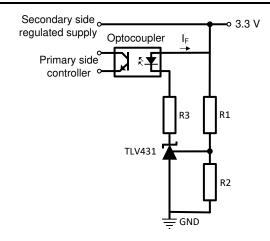
‡ Pin should be left floating or connect to anode

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Application Circuit



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit		
V_{KA}	Cathode Voltage	20	V		
IKA	Continuous Cathode Current	-20 to +20	mA		
I _{REF}	Reference Input Current Range	-0.05 to +3	mA		
ESD Susceptibility (N	ESD Susceptibility (Note 4)				
HBM	Human Body Model	4	kV		
MM	Machine Model	400	V		
CDM	Charged Device Model	1	kV		

Note: 4. Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.

Parameter	Rating	Unit
Operating Junction Temperature (Note 5)	-40 to +150	°C
Storage Temperature (Note 5)	-65 to +150	°C

Note

Recommended Operating Conditions (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Units
V_{KA}	Cathode Voltage	V_{REF}	18	V
I _{KA}	Cathode Current	0.1	15	mA
T _A	Operating Ambient Temperature Range	-40	+125	°C

Package Thermal Data

Package	θ _{JA}	P_{DIS} $T_A = +25^{\circ}C, T_J = +150^{\circ}C$
SOT23	380°C/W	330mW
SOT25	250°C/W	500mW
SC70-6 (SOT363)	380°C/W	330mW

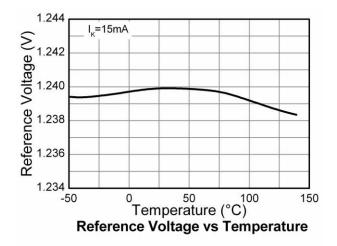
^{5.} Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. Unless otherwise stated voltages specified are relative to the ANODE pin. These are stress ratings only. Operation outside the absolute maximum ratings may cause device failure.

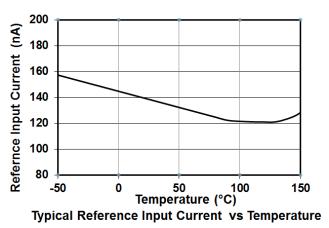


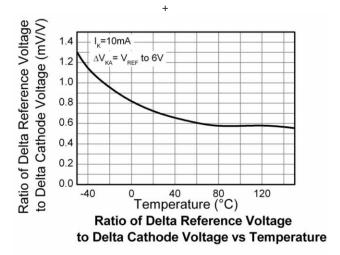
Symbol	Parameter	Cond	itions	Min	Тур	Max	Units
		V _{KA} = V _{REF} ,	TLV431A	1.228	1.24	1.252	
			TLV431B	1.234	1.24	1.246	
		$T_A = +25^{\circ}C$	TLV431T	1.2375	1.24	1.2425	
		W W	TLV431A	1.221	_	1.259	
		$V_{KA} = V_{REF},$ $T_A = 0^{\circ}C \text{ to } +70^{\circ}C$	TLV431B	1.227	_	1.253	
V_{REF}	Reference Voltage	1A = 0 C 10 +70 C	TLV431T	1.230	_	1.250	V
V REF	helefelice voltage	V _{KA} = V _{REF} ,	TLV431A	1.215	_	1.265	
		$V_{KA} = V_{REF}$, $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	TLV431B	1.224	_	1.259	
		TA = -40 C t0 +65 C	TLV431T	1.228	_	1.262	
		VKA = VREE.	TLV431A	1.209	_	1.271	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	TLV431B	1.221	_	1.265	
		TA = -40 O to +125 O	TLV431T	1.224	_	1.255	_
	Deviation of Reference Voltage Over Full	V _{KA} = V _{REF}	$T_A = 0$ °C to +70°C	_	4	12	mV
V _{REF(dev)}			$T_A = -40$ °C to $+85$ °C	_	6	20	
	Temperature Range		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	_	11	31	
ΔV _{REF}	Ratio of Change in Reference Voltage to	VKA for VBEE to	6V	_	-1.5	-2.7	mV/V
ΔV_{KA}	Change in Cathode Voltage	VAX 101 VREF 10	18V	_	-1.5	-2.7	111 V / V
I _{REF}	Reference Input Current	$R_1 = 10k\Omega$, $R_2 = OC$		_	0.15	0.5	μΑ
	I _{REF} Deviation Over	D 401.0	$T_A = 0$ °C to +70°C	_	0.05	0.3	
I _{REF(dev)}	Full Temperature	' '	$T_A = -40$ °C to $+85$ °C	_	0.1	0.4	μΑ
	Range	$R_2 = OC$	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	_	0.15	0.5	
			$T_A = 0$ °C to +70°C	_	55	80	
I _{KMIN}	Minimum Cathode	$V_{KA} = V_{REF}$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		55	80	μΑ
	Current for Regulation		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	_	55	100	
I _{K(OFF)}	Off State Current	V _{KA} = 18V, V _{REF} = 0V		_	0.001	0.1	μΑ
Z _{KA}	Dynamic Output Impedance	$V_{KA} = V_{REF}, f = <1kHz$ $I_K = 0.1mA \text{ to } 15mA$		_	0.25	0.4	Ω

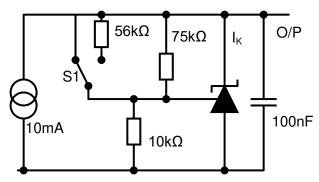


Typical Characteristics





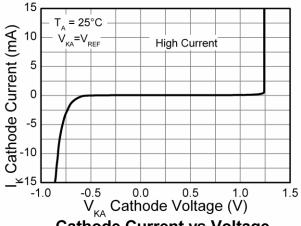




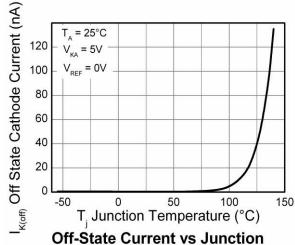
Test Circuit for V_{REF} Measurement



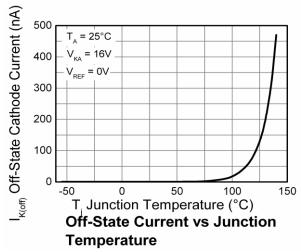
Typical Characteristics (continued)

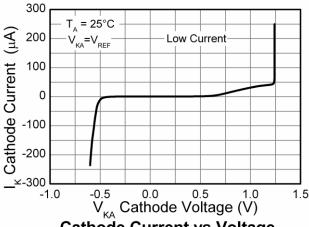




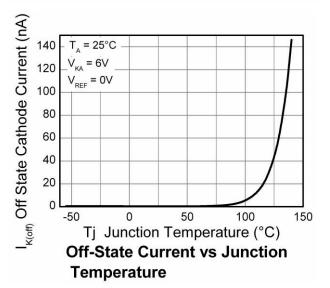


Temperature





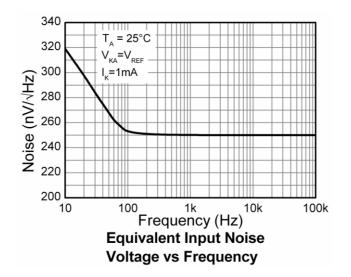
Cathode Current vs Voltage

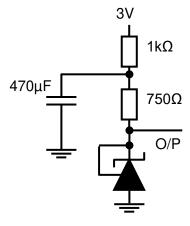


(nA) Off-State Cathode Current (nA) 600 $T_A = 25^{\circ}C$ V_{KA} = 18V 500 400 300 200 100 50 100 T_i Junction Temperature (°C) Off-state Current vs Junction **Temperature**

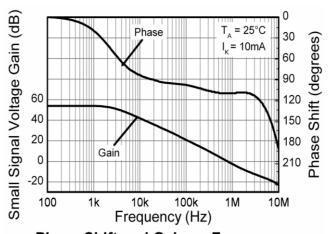


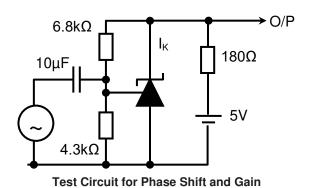
Typical Characteristics (continued)



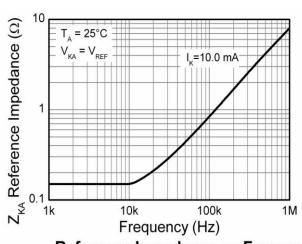


Test Circuit for Input Noise Voltage





Phase Shift and Gain vs Frequency

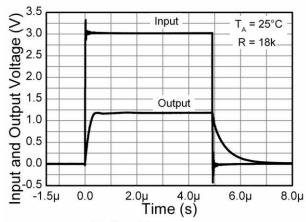


 $100\mu F$ 100Ω 100Ω 100Ω Test Circuit for Reference Impedance

Reference Impedance vs Frequency



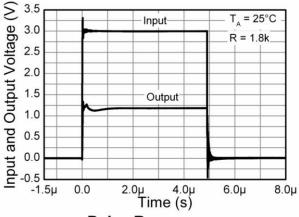
Typical Characteristics (continued)



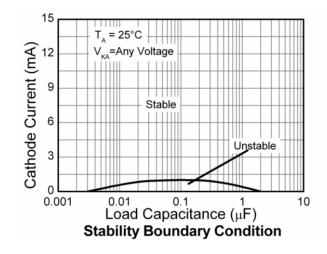
Pulse Generator

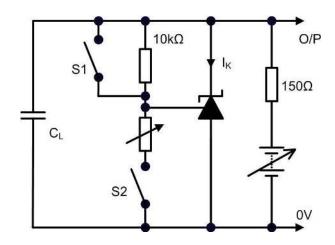
Test Circuit for Pulse Response

Pulse Response



Pulse Response





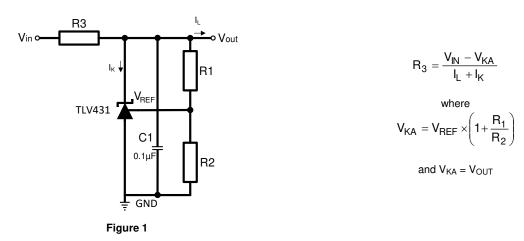


Application Notes

In a conventional shunt regulator application (Figure 1), an external series resistor (R_3) is connected between the supply voltage, V_{IN} , and the TLV431.

 R_3 determines the current that flows through the load (I_L) and the TLV431 (I_K). The TLV431 adjusts how much current it sinks or "shunts" to maintain a voltage equal to V_{REF} across its feedback pin. Because load current and supply voltage may vary, R_3 should be small enough to supply at least the minimum acceptable I_{KMIN} to the TLV431, even when the supply voltage is at its minimum and the load current is at its maximum value. When the supply voltage is at its maximum and I_L is at its minimum, R_3 should be large enough so that the current flowing through the TLV431 is less than 15mA.

R₃ is determined by the supply voltage, (V_{IN}), the load and operating current, (I_L and I_K), and the TLV431's reverse breakdown voltage, V_{KA}.



The values of R1 and R2 should be large enough so that the current flowing through them is much smaller than the current through R3, yet not too large that the voltage drop across them causes I_{REF} to affect the reference accuracy.

The most frequent application of the TLV431 is in isolated, low-output voltage power supplies where the regulated output is galvanically isolated from the controller. As shown in Figure 2, the TLV431 drives current, I_F, through the optocoupler's LED, which in turn drives the isolated transistor that is connected to the controller on the primary side of the power supply.

This completes the feedback path through the isolation barrier and ensures that a stable isolated supply is maintained.

Assuming a forward drop of 1.4V across the optocoupler diode allows output voltages as low as 2.7V to be regulated.

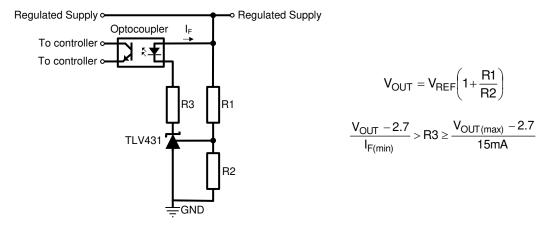


Figure 2. Using the TLV431 as the Regulating Element in an Isolated PSU



Application Notes (continued)

Printed Circuit Board Layout Considerations

The TLV431 in the SOT25 package has the die attached to pin 2, which results in an electrical contact between pin 2 and pin 5. Therefore, pin 2 of the SOT25 package must be left floating or connected to pin 5.

The TLV431 in the SC70-6 (SOT363) package has the die attached to pin 2 and 5, which results in an electrical contact between pins 2, 5, and pin 6. Therefore, pins 2 and 5 must be left floating or connected to pin 6.

Other Applications of the TLV431

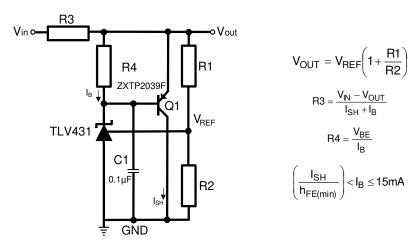


Figure 3. High Current Shunt Regulator

It may at times be required to shunt-regulate more current than the 15mA that which the TLV431 is capable.

Figure 3 shows how this can be done using transistor Q1 to amplify the TLV431's current. Care must be taken so the power dissipation and/or SOA requirements of the transistor is not exceeded.

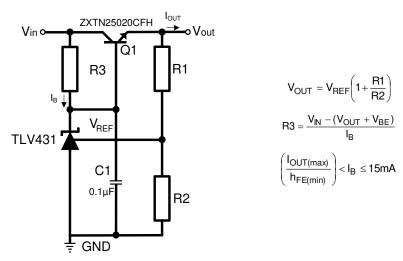


Figure 4. Basic Series Regulator

A very effective and simple series regulator can be implemented as shown in Figure 4. This may be preferable if the load requires more current than can be provided by the TLV431 alone, and conserving power when the load is not being powered is required. This circuit also uses one component less than the shunt circuit shown in Figure 3.



Application Notes (continued)

Printed Circuit Board Layout Considerations (continued)

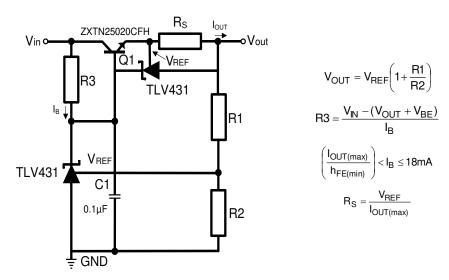


Figure 5. Series Regulator with Current Limit

Figure 5 adds current limit to the series regulator in Figure 4 by using a second TLV431. For currents below the limit, the circuit works normally supplying the required load current at the design voltage. However should attempts be made to exceed the design current set by the second TLV431, the device begins to shunt current away from the base of Q1. This begins to reduce the output voltage and thus ensuring that the output current is clamped at the design value. Subject only to Q1's ability to withstand the resulting power dissipation, the circuit can withstand either a brief or indefinite short circuit.

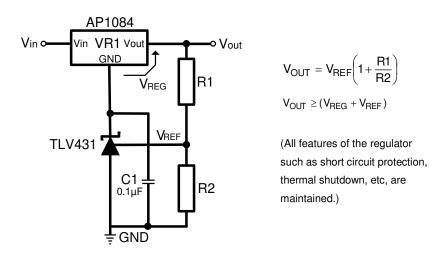


Figure 6. Increasing Output Voltage of a Fixed Linear Regulator

One of the useful applications of the TLV431 is to improve the accuracy and/or extend the range and flexibility of fixed-voltage regulators. In the Figure 6 circuit, both the output voltage and its accuracy are entirely determined by the TLV431, R1, and R2. However, the rest of the features of the regulator (up to 5A output current, output current limiting, and thermal shutdown) are all still available.



Application Notes (continued)

Printed Circuit Board Layout Considerations (continued)

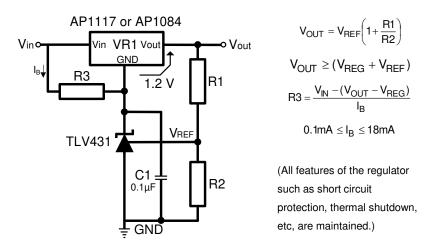


Figure 7. Adjustable Linear Voltage Regulator

Figure 7 is similar to Figure 6 with adjustability added. Note the addition of R3. This is only required for the AP1117 due to the fact that its ground or adjustment pin can only supply a few mA of current at best. Therefore, R3 must provide sufficient bias current for the TLV431.

Ordering Information

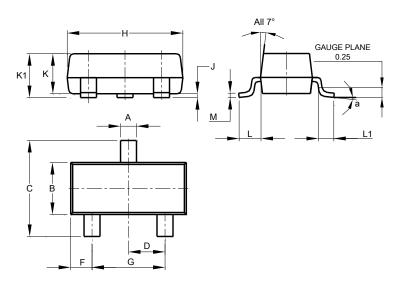
Tol.	Orderable Part Number	Package	Part Mark	Status	Reel Size	Tape Width	Quanity per Reel
	TLV431AE5TA	SOT25	V1A	Active	7", 180mm	8mm	3,000
1%	TLV431AFTA	SOT23	V1A	Active	7", 180mm	8mm	3,000
170	TLV431AH6TA	SC70-6 (SOT363)	V1A	Active	7", 180mm	8mm	3,000
	TLV431BE5TA	SOT25	V1B	Active	7", 180mm	8mm	3,000
0.5%	TLV431BFTA	SOT23	V1B	Active	7", 180mm	8mm	3,000
0.576	TLV431BH6TA	SC70-6 (SOT363)	V1B	Active	7", 180mm	8mm	3,000
0.2%	TLV431TFTA	SOT23	V1T	Active	7", 180mm	8mm	3,000



Package Outline Dimensions (All dimensions in mm.)

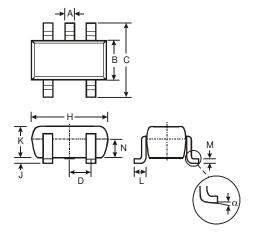
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



SOT23				
Dim	Min	Max	Тур	
Α	0.37	0.51	0.40	
В	1.20	1.40	1.30	
C	2.30	2.50	2.40	
D	0.89	1.03	0.915	
F	0.45	0.60	0.535	
G	1.78	2.05	1.83	
Н	2.80	3.00	2.90	
J	0.013	0.10	0.05	
K	0.890	1.00	0.975	
K1	0.903	1.10	1.025	
L	0.45	0.61	0.55	
L1	0.25	0.55	0.40	
М	0.085	0.150	0.110	
а	0°	8°		
All Dimensions in mm				

SOT25

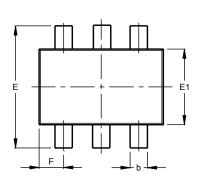


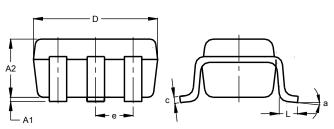
	SOT25					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	-	-	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
М	0.10	0.20	0.15			
N	0.70	0.80	0.75			
α	0°	8°	-			
All Dimensions in mm						



Package Outline Dimensions (All dimensions in mm.) (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.





SOT363

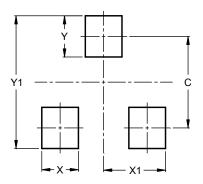
	SOT363				
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.90	1.00	0.95		
Ь	0.10	0.30	0.25		
С	0.10	0.22	0.11		
D	1.80	2.20	2.15		
Е	2.00	2.20	2.10		
E1	1.15	1.35	1.30		
е	C	.650 E	SC		
F	0.40	0.45	0.425		
L	0.25	0.40	0.30		
а	0°	8°			
All I	Dimen	sions	in mm		



Suggested Pad Layout

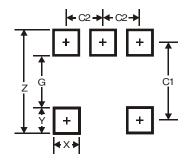
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



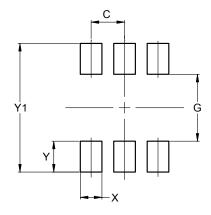
Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9

SOT25



Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95

SOT363



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
Y1	2.500



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